NSN 5961-00-958-5416

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-958-5416 **Inclosure Material:** Metal **Overall Length:** 0.400 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 breakover voltage, dc **Current Rating Per Characteristic:** 3.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug **Specification Data:** 80131-release3171 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0